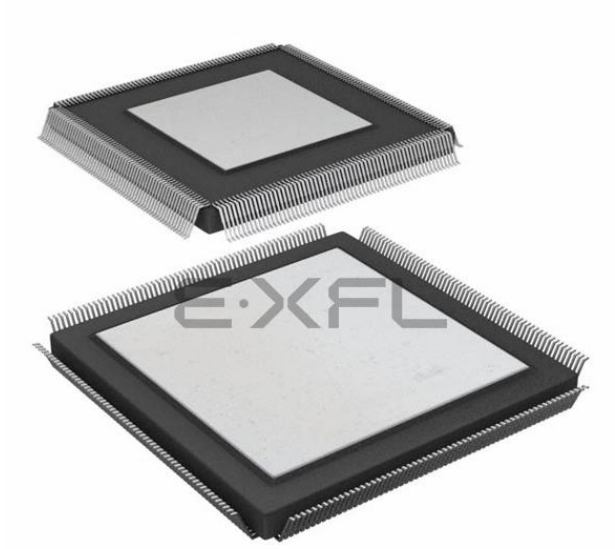


Welcome to E-XFL.COM

Understanding Embedded - DSP (Digital Signal Processors)

Embedded - DSP (Digital Signal Processors) are specialized microprocessors designed to perform complex mathematical computations on digital signals in real-time. Unlike general-purpose processors, DSPs are optimized for high-speed numeric processing tasks, making them ideal for applications that require efficient and precise manipulation of digital data. These processors are fundamental in converting and processing signals in various forms, including audio, video, and communication signals, ensuring that data is accurately interpreted and utilized in embedded systems.

Applications of Embedded - DSP (Digital Signal Processors)

Details	
Product Status	Active
Type	Floating Point
Interface	Host Interface, Link Port, Serial Port
Clock Rate	40MHz
Non-Volatile Memory	External
On-Chip RAM	512kB
Voltage - I/O	5.00V
Voltage - Core	5.00V
Operating Temperature	-40°C ~ 100°C (TC)
Mounting Type	Surface Mount
Package / Case	240-BFCQFP Exposed Pad
Supplier Device Package	240-CQFP (32x32)
Purchase URL	https://www.e-xfl.com/product-detail/analog-devices/adsp-21060cz-160

Algorithmic Modules

To speed development, Analog Devices offers add-ins that perform popular audio and video processing algorithms. These are available for use with both CrossCore Embedded Studio and VisualDSP++. For more information visit www.analog.com and search on "Blackfin software modules" or "SHARC software modules".

Designing an Emulator-Compatible DSP Board (Target)

For embedded system test and debug, Analog Devices provides a family of emulators. On each JTAG DSP, Analog Devices supplies an IEEE 1149.1 JTAG Test Access Port (TAP). In-circuit emulation is facilitated by use of this JTAG interface. The emulator accesses the processor's internal features via the processor's TAP, allowing the developer to load code, set breakpoints, and view variables, memory, and registers. The processor must be halted to send data and commands, but once an operation is completed by the emulator, the DSP system is set to run at full speed with no impact on system timing. The emulators require the target board to include a header that supports connection of the DSP's JTAG port to the emulator.

For details on target board design issues including mechanical layout, single processor connections, signal buffering, signal termination, and emulator pod logic, see the *EE-68: Analog Devices JTAG Emulation Technical Reference* on the Analog Devices website (www.analog.com)—use site search on "EE-68." This document is updated regularly to keep pace with improvements to emulator support.

ADDITIONAL INFORMATION

This data sheet provides a general overview of the ADSP-2106x architecture and functionality. For detailed information on the ADSP-21000 family core architecture and instruction set, refer to the *ADSP-2106x SHARC User's Manual*, Revision 2.1.

RELATED SIGNAL CHAINS

A *signal chain* is a series of signal-conditioning electronic components that receive input (data acquired from sampling either real-time phenomena or from stored data) in tandem, with the output of one portion of the chain supplying input to the next. Signal chains are often used in signal processing applications to gather and process data or to apply system controls based on analysis of real-time phenomena. For more information about this term and related topics, see the "signal chain" entry in the Glossary of EE Terms on the Analog Devices website.

Analog Devices eases signal processing system development by providing signal processing components that are designed to work together well. A tool for viewing relationships between specific applications and related components is available on the www.analog.com website.

The Application Signal Chains page in the Circuits from the Lab™ site (http://www.analog.com/signalchains) provides:

- Graphical circuit block diagram presentation of signal chains for a variety of circuit types and applications
- Drill down links for components in each chain to selection guides and application information
- Reference designs applying best practice design techniques

Table 3. Pin Descriptions (Continued)

Pin	Type	Function
ACK	I/O/S	**Memory Acknowledge.** External devices can deassert ACK (low) to add wait states to an external memory access. ACK is used by I/O devices, memory controllers, or other peripherals to hold off completion of an external memory access. The ADSP-2106x deasserts ACK as an output to add waitstates to a synchronous access of its internal memory. In a multiprocessing system, a slave ADSP-2106x deasserts the bus master's ACK input to add wait state(s) to an access of its internal memory. The bus master has a keeper latch on its ACK pin that maintains the input at the level to which it was last driven.
$\overline{\text{SBTS}}$	I/S	**Suspend Bus Three-State.** External devices can assert $\overline{\text{SBTS}}$ (low) to place the external bus address, data, selects, and strobes in a high impedance state for the following cycle. If the ADSP-2106x attempts to access external memory while $\overline{\text{SBTS}}$ is asserted, the processor will halt and the memory access will not be completed until $\overline{\text{SBTS}}$ is deasserted. $\overline{\text{SBTS}}$ should only be used to recover from host processor/ADSP-2106x deadlock, or used with a DRAM controller.
$\overline{\text{IRQ2–0}}$	I/A	**Interrupt Request Lines.** May be either edge-triggered or level-sensitive.
FLAG3–0	I/O/A	**Flag Pins.** Each is configured via control bits as either an input or output. As an input, they can be tested as a condition. As an output, they can be used to signal external peripherals.
TIMEXP	O	**Timer Expired.** Asserted for four cycles when the timer is enabled and TCOUNT decrements to zero.
$\overline{\text{HBR}}$	I/A	**Host Bus Request.** This pin must be asserted by a host processor to request control of the ADSP-2106x's external bus. When $\overline{\text{HBR}}$ is asserted in a multiprocessing system, the ADSP-2106x that is bus master will relinquish the bus and assert $\overline{\text{HBG}}$. To relinquish the bus, the ADSP-2106x places the address, data, select and strobe lines in a high impedance state. $\overline{\text{HBR}}$ has priority over all ADSP-2106x bus requests $\overline{\text{BR6–1}}$ in a multiprocessing system.
$\overline{\text{HBG}}$	I/O	**Host Bus Grant.** Acknowledges a bus request, indicating that the host processor may take control of the external bus. $\overline{\text{HBG}}$ is asserted (held low) by the ADSP-2106x until $\overline{\text{HBR}}$ is released. In a multiprocessing system, $\overline{\text{HBG}}$ is output by the ADSP-2106x bus master and is monitored by all others.
$\overline{\text{CS}}$	I/A	**Chip Select.** Asserted by host processor to select the ADSP-2106x.
REDY	O (O/D)	**Host Bus Acknowledge.** The ADSP-2106x deasserts REDY (low) to add wait states to an asynchronous access of its internal memory or IOP registers by a host. This pin is an open-drain output (O/D) by default; it can be programmed in the ADREDY bit of the SYSCON register to be active drive (A/D). REDY will only be output if the $\overline{\text{CS}}$ and $\overline{\text{HBR}}$ inputs are asserted.
$\overline{\text{DMAR2–1}}$	I/A	**DMA Request 1** (DMA Channel 7) and **DMA Request 2** (DMA Channel 8).
$\overline{\text{DMAG2–1}}$	O/T	**DMA Grant 1** (DMA Channel 7) and **DMA Grant 2** (DMA Channel 8).
$\overline{\text{BR6–1}}$	I/O/S	**Multiprocessing Bus Requests.** Used by multiprocessing ADSP-2106xs to arbitrate for bus master-ship. An ADSP-2106x only drives its own $\overline{\text{BR}}$x line (corresponding to the value of its ID2-0 inputs) and monitors all others. In a multiprocessor system with less than six ADSP-2106xs, the unused $\overline{\text{BR}}$x pins should be pulled high; the processor's own $\overline{\text{BR}}$x line must not be pulled high or low because it is an output.
$\overline{\text{ID2–0}}$	O (O/D)	**Multiprocessing ID.** Determines which multiprocessing bus request ($\overline{\text{BR1}}$– $\overline{\text{BR6}}$) is used by ADSP-2106x. ID = 001 corresponds to $\overline{\text{BR1}}$, ID = 010 corresponds to $\overline{\text{BR2}}$, etc. ID = 000 in single-processor systems. These lines are a system configuration selection that should be hardwired or changed at reset only.
RPBA	I/S	**Rotating Priority Bus Arbitration Select.** When RPBA is high, rotating priority for multiprocessor bus arbitration is selected. When RPBA is low, fixed priority is selected. This signal is a system configuration selection that must be set to the same value on every ADSP-2106x. If the value of RPBA is changed during system operation, it must be changed in the same CLKIN cycle on every ADSP-2106x.
$\overline{\text{CPA}}$	I/O (O/D)	**Core Priority Access.** Asserting its $\overline{\text{CPA}}$ pin allows the core processor of an ADSP-2106x bus slave to interrupt background DMA transfers and gain access to the external bus. $\overline{\text{CPA}}$ is an open drain output that is connected to all ADSP-2106xs in the system. The $\overline{\text{CPA}}$ pin has an internal 5 kΩ pull-up resistor. If core access priority is not required in a system, the $\overline{\text{CPA}}$ pin should be left unconnected.
DTx	O	**Data Transmit (Serial Ports 0, 1).** Each DT pin has a 50 kΩ internal pull-up resistor.
DRx	I	**Data Receive (Serial Ports 0, 1).** Each DR pin has a 50 kΩ internal pull-up resistor.
TCLKx	I/O	**Transmit Clock (Serial Ports 0, 1).** Each TCLK pin has a 50 kΩ internal pull-up resistor.
RCLKx	I/O	**Receive Clock (Serial Ports 0, 1).** Each RCLK pin has a 50 kΩ internal pull-up resistor.

A = Asynchronous, G = Ground, I = Input, O = Output, P = Power Supply, S = Synchronous, (A/D) = Active Drive, (O/D) = Open Drain, T = Three-State (when $\overline{\text{SBTS}}$ is asserted, or when the ADSP-2106x is a bus slave)

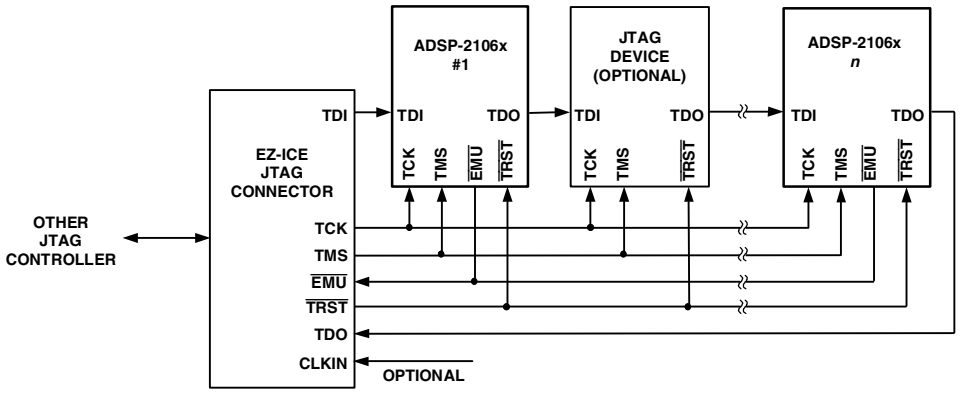


Figure 6. JTAG Scan Path Connections for Multiple ADSP-2106x Systems

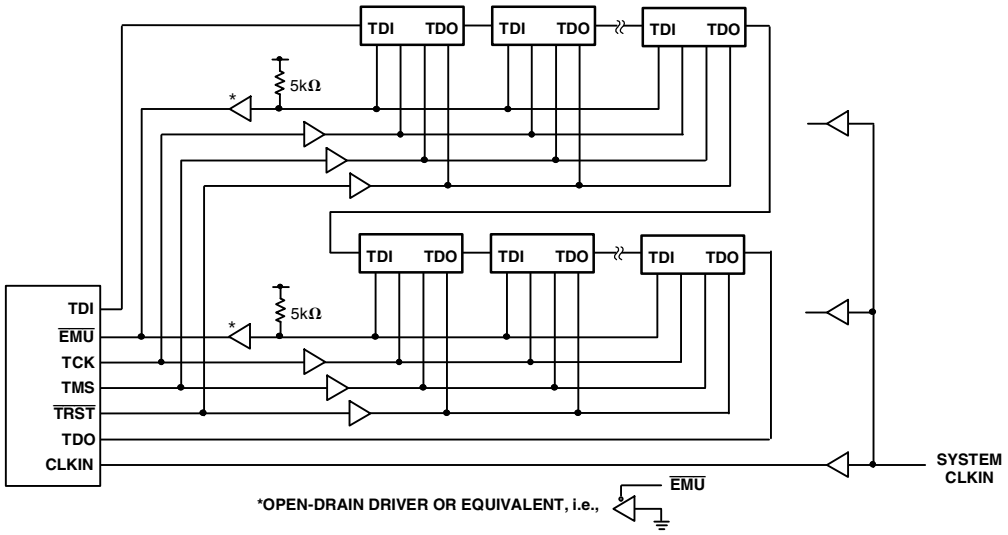


Figure 7. JTAG Clock Tree for Multiple ADSP-2106x Systems

EXTERNAL POWER DISSIPATION (5 V)

Total power dissipation has two components, one due to internal circuitry and one due to the switching of external output drivers. Internal power dissipation is dependent on the instruction execution sequence and the data operands involved. Internal power dissipation is calculated in the following way:

$$P_{INT} = I_{DDIN} \times V_{DD}$$

The external component of total power dissipation is caused by the switching of output pins. Its magnitude depends on:

- the number of output pins that switch during each cycle (O)
- the maximum frequency at which they can switch (f)
- their load capacitance (C)
- their voltage swing (V_{DD})

and is calculated by:

$$P_{EXT} = O \times C \times V_{DD}^2 \times f$$

The load capacitance should include the processor's package capacitance (CIN). The switching frequency includes driving the load high and then back low. Address and data pins can drive high and low at a maximum rate of $1/(2t_{CK})$. The write strobe can switch every cycle at a frequency of $1/t_{CK}$. Select pins switch at $1/(2t_{CK})$, but selects can switch on each cycle.

Example: Estimate P_{EXT} with the following assumptions:

- A system with one bank of external data memory RAM (32-bit)
- Four 128K × 8 RAM chips are used, each with a load of 10 pF
- External data memory writes occur every other cycle, a rate of $1/(4t_{CK})$, with 50% of the pins switching
- The instruction cycle rate is 40 MHz (t_{CK} = 25 ns)

The P_{EXT} equation is calculated for each class of pins that can drive:

A typical power consumption can now be calculated for these conditions by adding a typical internal power dissipation:

$$P_{TOTAL} = P_{EXT} + (I_{DDIN2} \times 5.0\ V)$$

Note that the conditions causing a worst-case P_{EXT} are different from those causing a worst-case P_{INT}. Maximum P_{INT} cannot occur while 100% of the output pins are switching from all ones to all zeros. Note also that it is not common for an application to have 100% or even 50% of the outputs switching simultaneously.

Table 5. External Power Calculations (5 V Devices)

Pin Type	No. of Pins	% Switching	× C	× f	× V_{DD}^2	= P_{EXT}
Address	15	50	× 44.7 pF	× 10 MHz	× 25 V	= 0.084 W
$\overline{MS0}$	1	0	× 44.7 pF	× 10 MHz	× 25 V	= 0.000 W
$\overline{WR}$	1	–	× 44.7 pF	× 20 MHz	× 25 V	= 0.022 W
Data	32	50	× 14.7 pF	× 10 MHz	× 25 V	= 0.059 W
ADDRCLK	1	–	× 4.7 pF	× 20 MHz	× 25 V	= 0.002 W
						P_{EXT} = 0.167 W

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PACKAGE MARKING INFORMATION

Figure 8 and Table 8 provide information on detail contained within the package marking for the ADSP-2106x processors (actual marking format may vary). For a complete listing of product availability, see Ordering Guide on Page 62.

Figure 8. Typical Package Brand

Table 8. Package Brand Information

Brand Key	Field Description
t	Temperature Range
pp	Package Type
Z	Lead (Pb) Free Option
ccc	See Ordering Guide
vvvvvv.x	Assembly Lot Code
n.n	Silicon Revision
yyww	Date Code

TIMING SPECIFICATIONS

The ADSP-2106x processors are available at maximum processor speeds of 33 MHz (–133), and 40 MHz (–160). The timing specifications are based on a CLKIN frequency of 40 MHz (t_{CK} = 25 ns). The DT derating factor enables the calculation for timing specifications within the min to max range of the t_{CK} specification (see Table 9). DT is the difference between the derated CLKIN period and a CLKIN period of 25 ns:

$$DT = t_{CK} - 25 \text{ ns}$$

Use the exact timing information given. Do not attempt to derive parameters from the addition or subtraction of others. While addition or subtraction would yield meaningful results for an individual device, the values given in this data sheet reflect statistical variations and worst cases. Consequently, you cannot meaningfully add parameters to derive longer times.

For voltage reference levels, see Figure 28 on Page 48 under Test Conditions.

Timing Requirements apply to signals that are controlled by circuitry external to the processor, such as the data input for a read operation. Timing requirements guarantee that the processor operates correctly with other devices. (O/D) = Open Drain, (A/D) = Active Drive.

Switching Characteristics specify how the processor changes its signals. You have no control over this timing—circuitry external to the processor must be designed for compatibility with these signal characteristics. Switching characteristics tell you what the processor will do in a given circumstance. You can also use switching characteristics to ensure that any timing requirement of a device connected to the processor (such as memory) is satisfied.

Interrupts

Table 11. Interrupts

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Timing Requirements				
t_{SIR}	$\overline{IRQ2–0}$ Setup Before CLKIN High[1]	18 + 3DT/4		ns
t_{HIR}	$\overline{IRQ2–0}$ Hold Before CLKIN High[1]		12 + 3DT/4	ns
t_{IPW}	$\overline{IRQ2–0}$ Pulse Width[2]	$2+t_{CK}$		ns

[1] Only required for $\overline{IRQx}$ recognition in the following cycle.
[2] Applies only if t_{SIR} and t_{HIR} requirements are not met.

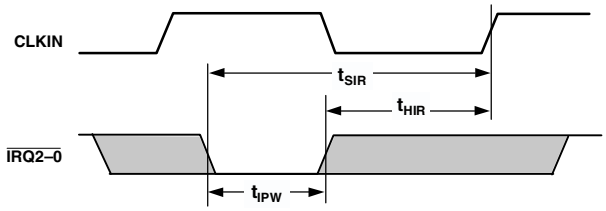


Figure 11. Interrupts

Timer

Table 12. Timer

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Switching Characteristic				
t_{DTEX}	CLKIN High to TIMEXP		15	ns

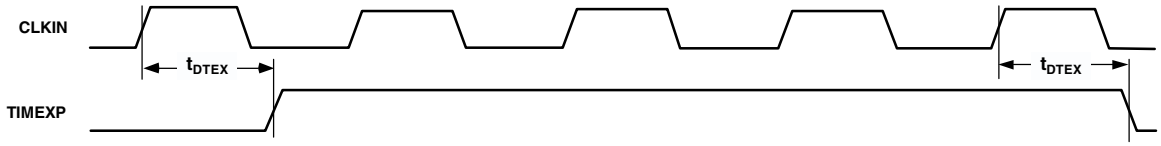


Figure 12. Timer

Flags

Table 13. Flags

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Timing Requirements				
t_{SFI}	FLAG3–0 IN Setup Before CLKIN High[1]	8 + 5DT/16		ns
t_{HFI}	FLAG3–0 IN Hold After CLKIN High[1]	0 – 5DT/16		ns
t_{DWRFI}	FLAG3–0 IN Delay After $\overline{RD}/\overline{WR}$ Low[1]		5 + 7DT/16	ns
t_{HFIWR}	FLAG3–0 IN Hold After $\overline{RD}/\overline{WR}$ Deasserted[1]	0		ns
Switching Characteristics				
t_{DFO}	FLAG3–0 OUT Delay After CLKIN High		16	ns
t_{HFO}	FLAG3–0 OUT Hold After CLKIN High	4		ns
t_{DFOE}	CLKIN High to FLAG3–0 OUT Enable	3		ns
t_{DFOD}	CLKIN High to FLAG3–0 OUT Disable		14	ns

[1] Flag inputs meeting these setup and hold times for instruction cycle N will affect conditional instructions in instruction cycle N+2.

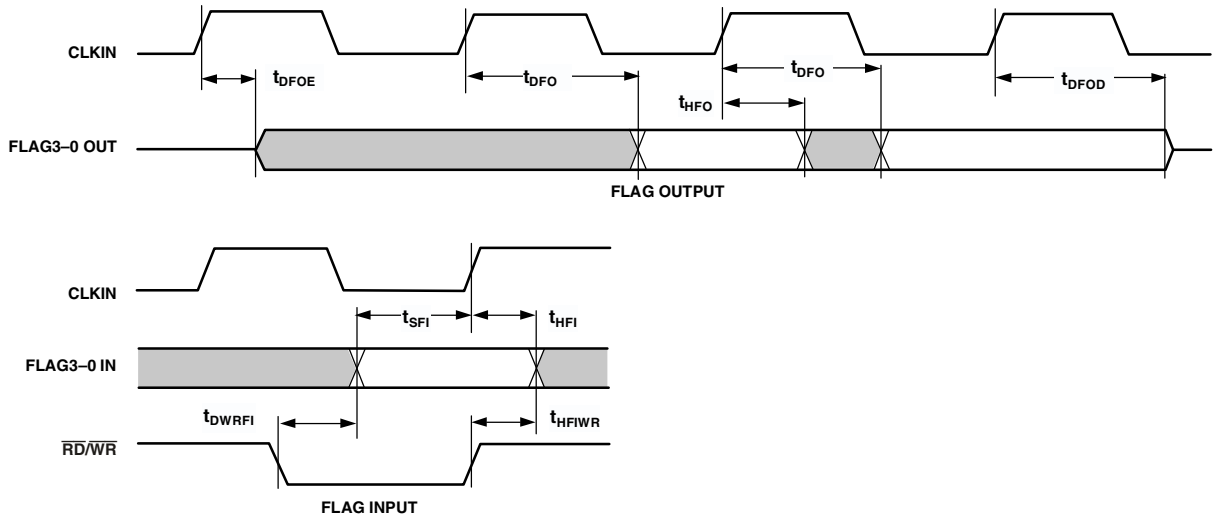


Figure 13. Flags

Memory Write—Bus Master

Use these specifications for asynchronous interfacing to memories (and memory-mapped peripherals) without reference to CLKIN. These specifications apply when the ADSP-2106x is the bus master accessing external memory space in asynchronous access mode. Note that timing for ACK, DATA, $\overline{RD}$, $\overline{WR}$, and $\overline{DMAGx}$ strobe timing parameters only applies to asynchronous access mode.

Table 15. Memory Write—Bus Master

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Timing Requirements				
t_{DAAK}	ACK Delay from Address, Selects[1, 2]		14 + 7DT/8 + W	ns
t_{DSAK}	ACK Delay from $\overline{WR}$ Low[1]		8 + DT/2 + W	ns
Switching Characteristics				
t_{DAWH}	Address Selects to $\overline{WR}$ Deasserted[2]	17 + 15DT/16 + W		ns
t_{DAWL}	Address Selects to $\overline{WR}$ Low[2]	3 + 3DT/8		ns
t_{WW}	$\overline{WR}$ Pulse Width	12 + 9DT/16 + W		ns
t_{DDWH}	Data Setup Before $\overline{WR}$ High	7 + DT/2 + W		ns
t_{DWHA}	Address Hold After $\overline{WR}$ Deasserted	0.5 + DT/16 + H		ns
t_{DATRWH}	Data Disable After $\overline{WR}$ Deasserted[3]	1 + DT/16 + H	6 + DT/16 + H	ns
t_{WWR}	$\overline{WR}$ High to $\overline{WR}$, $\overline{RD}$, $\overline{DMAGx}$ Low	8 + 7DT/16 + H		ns
t_{DDWR}	Data Disable Before $\overline{WR}$ or $\overline{RD}$ Low	5 + 3DT/8 + I		ns
t_{WDE}	$\overline{WR}$ Low to Data Enabled	–1 + DT/16		ns
t_{SADADC}	Address, Selects Setup Before ADRCLK High[2]	0 + DT/4		ns

W = (number of wait states specified in WAIT register) × t_{CK}.
H = t_{CK} (if an address hold cycle occurs, as specified in WAIT register; otherwise H = 0).
HI = t_{CK} (if an address hold cycle or bus idle cycle occurs, as specified in WAIT register; otherwise HI = 0).
I = t_{CK} (if a bus idle cycle occurs, as specified in WAIT register; otherwise I = 0).

[1] ACK is not sampled on external memory accesses that use the internal wait state mode. For the first CLKIN cycle of a new external memory access, ACK must be valid by t_{DAAK} or t_{DSAK} or synchronous specification t_{SACKC} for wait state modes external, either, or both (both, if the internal wait state is zero). For the second and subsequent cycles of a wait stated external memory access, synchronous specifications t_{SACKC} and t_{HACK} must be met for wait state modes external, either, or both (both, after internal wait states have completed).

[2] The falling edge of $\overline{MSx}$, $\overline{SW}$, $\overline{BMS}$ is referenced.

[3] See Example System Hold Time Calculation on Page 48 for calculation of hold times given capacitive and dc loads.

Synchronous Read/Write—Bus Master

Use these specifications for interfacing to external memory systems that require CLKIN—relative timing or for accessing a slave ADSP-2106x (in multiprocessor memory space). These synchronous switching characteristics are also valid during asynchronous memory reads and writes except where noted (see Memory Read—Bus Master on Page 25 and Memory Write—Bus Master on Page 26). When accessing a slave ADSP-2106x, these switching characteristics must meet the slave's timing requirements for synchronous read/writes (see Synchronous Read/Write—Bus Slave on Page 30). The slave ADSP-2106x must also meet these (bus master) timing requirements for data and acknowledge setup and hold times.

Table 16. Synchronous Read/Write—Bus Master

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Timing Requirements				
t_{SSDATI}	Data Setup Before CLKIN	3 + DT/8		ns
t_{HSDATI}	Data Hold After CLKIN	3.5 – DT/8		ns
t_{DAAK}	ACK Delay After Address, Selects[1, 2]		14 + 7DT/8 + W	ns
t_{SACKC}	ACK Setup Before CLKIN[2]	6.5 + DT/4		ns
t_{HACK}	ACK Hold After CLKIN	–1 – DT/4		ns
Switching Characteristics				
t_{DADRO}	Address, $\overline{MSx}$, $\overline{BMS}$, $\overline{SW}$ Delay After CLKIN[1]		7 – DT/8	ns
t_{HADRO}	Address, $\overline{MSx}$, $\overline{BMS}$, $\overline{SW}$ Hold After CLKIN	–1 – DT/8		ns
t_{DPGC}	PAGE Delay After CLKIN	9 + DT/8	16 + DT/8	ns
t_{DRDO}	$\overline{RD}$ High Delay After CLKIN	–2 – DT/8	4 – DT/8	ns
t_{DWRO}	$\overline{WR}$ High Delay After CLKIN	–3 – 3DT/16	4 – 3DT/16	ns
t_{DRWL}	$\overline{RD}$/$\overline{WR}$ Low Delay After CLKIN	8 + DT/4	12.5 + DT/4	ns
t_{SDDATO}	Data Delay After CLKIN		19 + 5DT/16	ns
t_{DATTR}	Data Disable After CLKIN[3]	0 – DT/8	7 – DT/8	ns
t_{DADCCK}	ADRCLK Delay After CLKIN	4 + DT/8	10 + DT/8	ns
t_{ADRCK}	ADRCLK Period	t_{CK}		ns
t_{ADRCKH}	ADRCLK Width High	(t_{CK}/2 – 2)		ns
t_{ADRCKL}	ADRCLK Width Low	(t_{CK}/2 – 2)		ns

[1] The falling edge of $\overline{MSx}$, $\overline{SW}$, $\overline{BMS}$ is referenced.

[2] ACK delay/setup: user must meet t_{DAAK} or t_{DSAK} or synchronous specification t_{SAKC} for deassertion of ACK (low), all three specifications must be met for assertion of ACK (high).

[3] See Example System Hold Time Calculation on Page 48 for calculation of hold times given capacitive and dc loads.

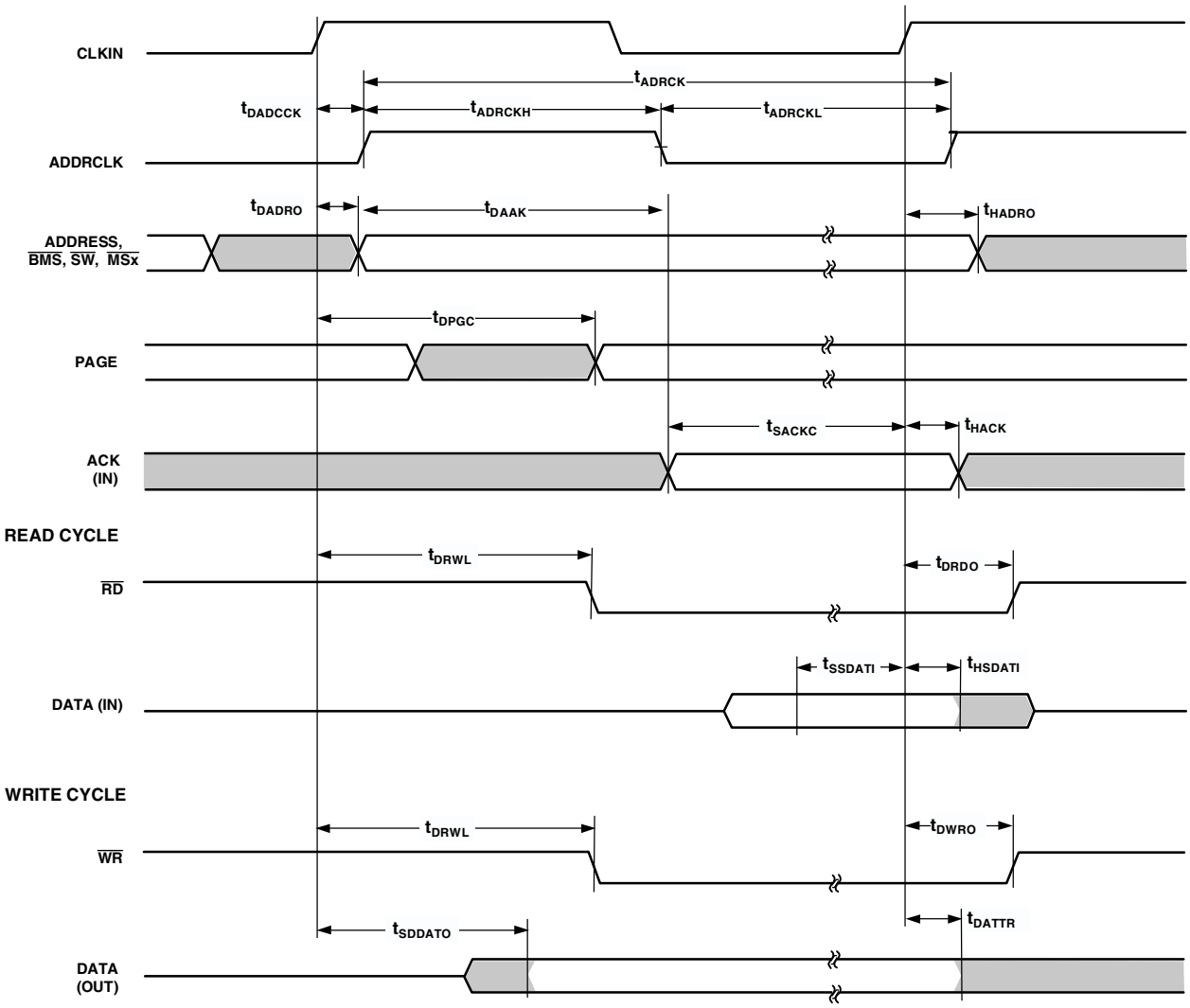


Figure 16. Synchronous Read/Write—Bus Master

Asynchronous Read/Write—Host to ADSP-2106x

Use these specifications for asynchronous host processor accesses of an ADSP-2106x, after the host has asserted $\overline{CS}$ and $\overline{HBR}$ (low). After $\overline{HBG}$ is returned by the ADSP-2106x, the host can drive the $\overline{RD}$ and $\overline{WR}$ pins to access the ADSP-2106x's internal memory or IOP registers. $\overline{HBR}$ and $\overline{HBG}$ are assumed low for this timing. Not required if and address are valid $t_{HBGRCSV}$ after goes low. For first access after asserted, ADDR31–0 must be a non-MMS value 1/2 t_{CLK} before or goes low or by $t_{HBGRCSV}$ after goes low. This is easily accomplished by driving an upper address signal high when is asserted. See the "Host Processor Control of the ADSP-2106x" section in the ADSP-2106x *SHARC User's Manual*, Revision 2.1.

Table 19. Read Cycle

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Timing Requirements				
t_{SADRDL}	Address Setup/$\overline{CS}$ Low Before $\overline{RD}$ Low[1]	0		ns
t_{HADRDH}	Address Hold/$\overline{CS}$ Hold Low After $\overline{RD}$	0		ns
t_{WRWH}	$\overline{RD}$/$\overline{WR}$ High Width	6		ns
$t_{DRDHRDY}$	$\overline{RD}$ High Delay After REDY (O/D) Disable	0		ns
$t_{DRDHRDY}$	$\overline{RD}$ High Delay After REDY (A/D) Disable	0		ns
Switching Characteristics				
$t_{SDATRDY}$	Data Valid Before REDY Disable from Low	2		ns
$t_{DRDYRDL}$	REDY (O/D) or (A/D) Low Delay After $\overline{RD}$ Low[2]		10	ns
t_{RDYPRD}	REDY (O/D) or (A/D) Low Pulse Width for Read	45 + 21DT/16		ns
t_{HDARWH}	Data Disable After $\overline{RD}$ High[3]	2	8	ns

[1] Not required if $\overline{RD}$ and address are valid $t_{HBGRCSV}$ after $\overline{HBG}$ goes low. For first access after $\overline{HBR}$ asserted, ADDR31-0 must be a non-MMS value 1/2 t_{CLK} before $\overline{RD}$ or $\overline{WR}$ goes low or by $t_{HBGRCSV}$ after $\overline{HBG}$ goes low. This is easily accomplished by driving an upper address signal high when $\overline{HBG}$ is asserted. See the "Host Processor Control of the ADSP-2106x" section in the ADSP-2106x *SHARC User's Manual,* Revision 2.1.

[2] For ADSP-21060L, specification is 10.5 ns max; for ADSP-21060LC, specification is 12.5 ns max.

[3] For ADSP-21060L/ADSP-21060LC, specification is 2 ns min, 8.5 ns max.

Table 20. Write Cycle

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Timing Requirements				
t_{SCSWRL}	$\overline{CS}$ Low Setup Before $\overline{WR}$ Low	0		ns
t_{HCSWRH}	$\overline{CS}$ Low Hold After $\overline{WR}$ High	0		ns
t_{SADWRH}	Address Setup Before $\overline{WR}$ High	5		ns
t_{HADWRH}	Address Hold After $\overline{WR}$ High	2		ns
t_{WWRL}	$\overline{WR}$ Low Width	7		ns
t_{WRWH}	$\overline{RD}$/$\overline{WR}$ High Width	6		ns
$t_{DWRHRDY}$	$\overline{WR}$ High Delay After REDY (O/D) or (A/D) Disable	0		ns
t_{SDATWH}	Data Setup Before $\overline{WR}$ High	5		ns
t_{HDATWH}	Data Hold After $\overline{WR}$ High	1		ns
Switching Characteristics				
$t_{DRDYWRL}$	REDY (O/D) or (A/D) Low Delay After $\overline{WR}$/$\overline{CS}$ Low		10	ns
t_{RDYPWR}	REDY (O/D) or (A/D) Low Pulse Width for Write	15 + 7DT/16		ns
t_{SRDYCK}	REDY (O/D) or (A/D) Disable to CLKIN	1 + 7DT/16	8 + 7DT/16	ns

Three-State Timing—Bus Master, Bus Slave

These specifications show how the memory interface is disabled (stops driving) or enabled (resumes driving) relative to CLKIN and the $\overline{\text{SBTS}}$ pin. This timing is applicable to bus master transition cycles (BTC) and host transition cycles (HTC) as well as the $\overline{\text{SBTS}}$ pin.

Table 21. Three-State Timing—Bus Master, Bus Slave

Parameter		5 V and 3.3 V Min	5 V and 3.3 V Max	Unit
Timing Requirements				
t_{STSCK}	$\overline{\text{SBTS}}$ Setup Before CLKIN	12 + DT/2		ns
t_{HTSCK}	$\overline{\text{SBTS}}$ Hold Before CLKIN		6 + DT/2	ns
Switching Characteristics				
t_{MIENA}	Address/Select Enable After CLKIN[1]	–1.5 – DT/8		ns
t_{MIENS}	Strobes Enable After CLKIN[2]	–1.5 – DT/8		ns
t_{MIENHG}	$\overline{\text{HBG}}$ Enable After CLKIN	–1.5 – DT/8		ns
t_{MITRA}	Address/Select Disable After CLKIN[3]		0 – DT/4	ns
t_{MITRS}	Strobes Disable After CLKIN[2]		1.5 – DT/4	ns
t_{MITRHG}	$\overline{\text{HBG}}$ Disable After CLKIN		2.0 – DT/4	ns
t_{DATEN}	Data Enable After CLKIN[4]	9 + 5DT/16		ns
t_{DATTR}	Data Disable After CLKIN[4]	0 – DT/8	7 – DT/8	ns
t_{ACKEN}	ACK Enable After CLKIN[4]	7.5 + DT/4		ns
t_{ACKTR}	ACK Disable After CLKIN[4]	–1 – DT/8	6 – DT/8	ns
t_{ADCEN}	ADRCLK Enable After CLKIN	–2 – DT/8		ns
t_{ADCTR}	ADRCLK Disable After CLKIN		8 – DT/4	ns
t_{MTRHBG}	Memory Interface Disable Before $\overline{\text{HBG}}$ Low[5]	0 + DT/8		ns
t_{MENHBG}	Memory Interface Enable After $\overline{\text{HBG}}$ High[5]	19 + DT		ns

[1] For ADSP-21060L/ADSP-21060LC/ADSP-21062L, specification is –1.25 – DT/8 ns min, for ADSP-21062, specification is –1 – DT/8 ns min.
[2] Strobes = $\overline{\text{RD}}$, $\overline{\text{WR}}$, PAGE, $\overline{\text{DMAG}}$, $\overline{\text{BMS}}$, $\overline{\text{SW}}$.
[3] For ADSP-21060LC, specification is 0.25 – DT/4 ns max.
[4] In addition to bus master transition cycles, these specs also apply to bus master and bus slave synchronous read/write.
[5] Memory Interface = Address, $\overline{\text{RD}}$, $\overline{\text{WR}}$, $\overline{\text{MSx}}$, $\overline{\text{SW}}$, PAGE, $\overline{\text{DMAGx}}$, and $\overline{\text{BMS}}$ (in EPROM boot mode).

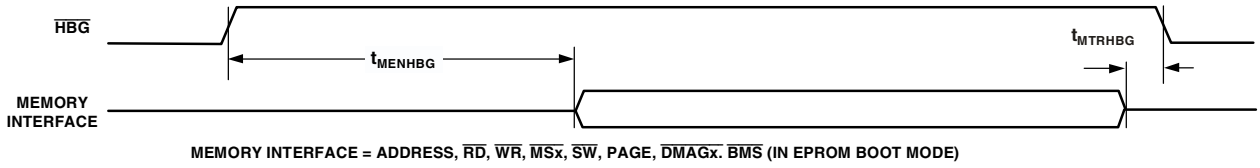


Figure 21. Three-State Timing (Bus Transition Cycle, $\overline{\text{SBTS}}$ Assertion)

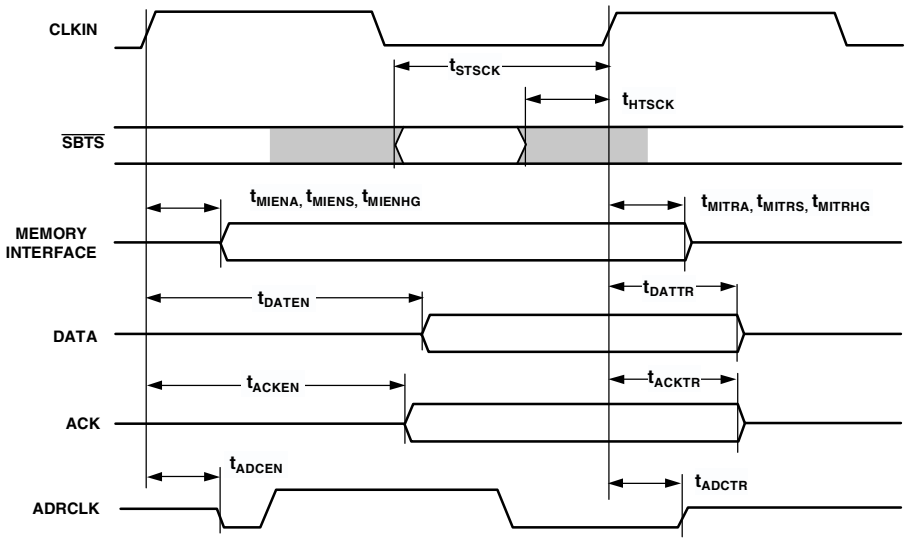


Figure 22. Three-State Timing (Bus Transition Cycle, $\overline{SBTS}$ Assertion)

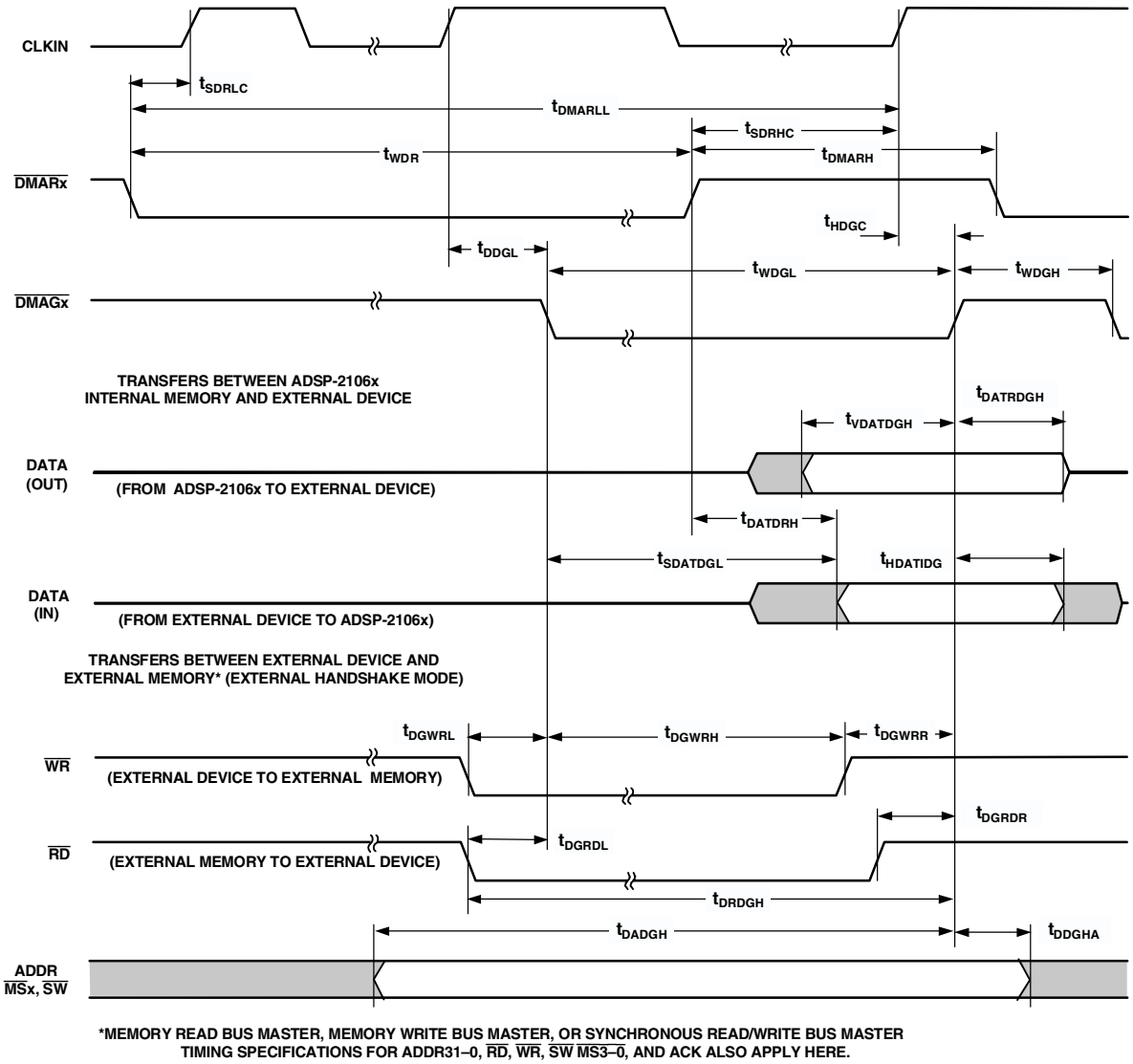


Figure 23. DMA Handshake

Serial Ports

For serial ports, see Table 28, Table 29, Table 30, Table 31, Table 32, Table 33, Table 35, Figure 26, and Figure 25. To determine whether communication is possible between two devices at clock speed n, the following specifications must be confirmed: 1) frame sync delay and frame sync setup and hold, 2) data delay and data setup and hold, and 3) SCLK width.

Table 28. Serial Ports—External Clock

Parameter		5 V and 3.3 V Min	Max	Unit
Timing Requirements				
t_{SFSE}	TFS/RFS Setup Before TCLK/RCLK[1]	3.5		ns
t_{HFSE}	TFS/RFS Hold After TCLK/RCLK[1, 2]	4		ns
t_{SDRE}	Receive Data Setup Before RCLK[1]	1.5		ns
t_{HDRE}	Receive Data Hold After RCLK[1]	6.5		ns
t_{SCLKW}	TCLK/RCLK Width[3]	9		ns
t_{SCLK}	TCLK/RCLK Period	t_{CK}		ns

[1] Referenced to sample edge.
[2] RFS hold after RCK when MCE = 1, MFD = 0 is 0 ns minimum from drive edge. TFS hold after TCK for late external TFS is 0 ns minimum from drive edge.
[3] For ADSP-21060/ADSP-21060C/ADSP-21060LC, specification is 9.5 ns min.

Table 29. Serial Ports—Internal Clock

Parameter		5 V and 3.3 V Min	Max	Unit
Timing Requirements				
t_{SFSI}	TFS Setup Before TCLK[1]; RFS Setup Before RCLK[1]	8		ns
t_{HFSI}	TFS/RFS Hold After TCLK/RCLK[1, 2]	1		ns
t_{SDRI}	Receive Data Setup Before RCLK[1]	3		ns
t_{HDRI}	Receive Data Hold After RCLK[1]	3		ns

[1] Referenced to sample edge.
[2] RFS hold after RCK when MCE = 1, MFD = 0 is 0 ns minimum from drive edge. TFS hold after TCK for late external TFS is 0 ns minimum from drive edge.

Table 30. Serial Ports—External or Internal Clock

Parameter		5 V and 3.3 V Min	Max	Unit
Switching Characteristics				
t_{DFSE}	RFS Delay After RCLK (Internally Generated RFS)[1]		13	ns
t_{HOFSE}	RFS Hold After RCLK (Internally Generated RFS)[1]	3		ns

[1] Referenced to drive edge.

Table 31. Serial Ports—External Clock

Parameter		5 V and 3.3 V Min	Max	Unit
Switching Characteristics				
t_{DFSE}	TFS Delay After TCLK (Internally Generated TFS)[1]		13	ns
t_{HOFSE}	TFS Hold After TCLK (Internally Generated TFS)[1]	3		ns
t_{DDTE}	Transmit Data Delay After TCLK[1]		16	ns
t_{HDTE}	Transmit Data Hold After TCLK[1]	5		ns

[1] Referenced to drive edge.

TEST CONDITIONS

For the ac signal specifications (timing parameters), see Timing Specifications on Page 21. These specifications include output disable time, output enable time, and capacitive loading. The timing specifications for the DSP apply for the voltage reference levels in Figure 28.

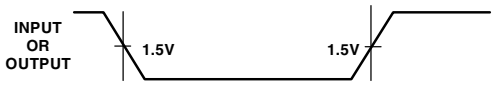


Figure 28. Voltage Reference Levels for AC Measurements (Except Output Enable/Disable)

Output Disable Time

Output pins are considered to be disabled when they stop driving, go into a high impedance state, and start to decay from their output high or low voltage. The time for the voltage on the bus to decay by ΔV is dependent on the capacitive load, C_L, and the load current, I_L. This decay time can be approximated by the following equation:

$$P_{EXT} = \frac{C_L \Delta V}{I_L}$$

The output disable time t_{DIS} is the difference between $t_{MEASURED}$ and t_{DECAY} as shown in Figure 29. The time $t_{MEASURED}$ is the interval from when the reference signal switches to when the output voltage decays ΔV from the measured output high or output low voltage. t_{DECAY} is calculated with test loads C_L and I_L, and with ΔV equal to 0.5 V.

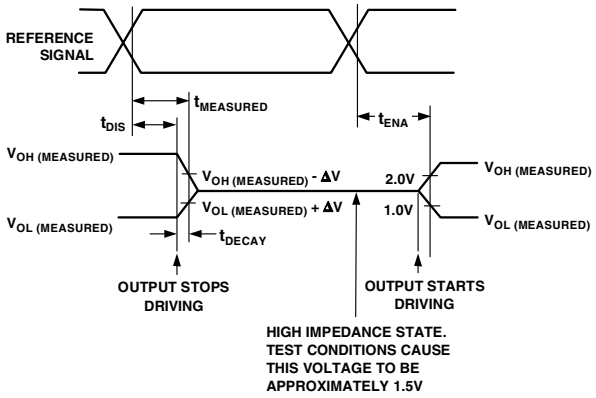


Figure 29. Output Enable/Disable

Output Enable Time

Output pins are considered to be enabled when they have made a transition from a high impedance state to when they start driving. The output enable time t_{ENA} is the interval from when a reference signal reaches a high or low voltage level to when the output has reached a specified high or low trip point, as shown in the Output Enable/Disable diagram (Figure 29). If multiple pins (such as the data bus) are enabled, the measurement value is that of the first pin to start driving.

Example System Hold Time Calculation

To determine the data output hold time in a particular system, first calculate t_{DECAY} using the equation given above. Choose ΔV to be the difference between the ADSP-2106x's output voltage and the input threshold for the device requiring the hold time. A typical ΔV will be 0.4 V. C_L is the total bus capacitance (per data line), and I_L is the total leakage or three-state current (per data line). The hold time will be t_{DECAY} plus the minimum disable time (i.e., t_{DATRWH} for the write cycle).

Capacitive Loading

Output delays and holds are based on standard capacitive loads: 50 pF on all pins (see Figure 30). The delay and hold specifications given should be derated by a factor of 1.5 ns/50 pF for loads other than the nominal value of 50 pF. Figure 32, Figure 33, Figure 37, and Figure 38 show how output rise time varies with capacitance. Figure 34 and Figure 36 show graphically how output delays and holds vary with load capacitance. (Note that this graph or derating does not apply to output disable delays; see the previous section Output Disable Time under Test Conditions.) The graphs of Figure 32, Figure 33, Figure 37, and Figure 38 may not be linear outside the ranges shown.

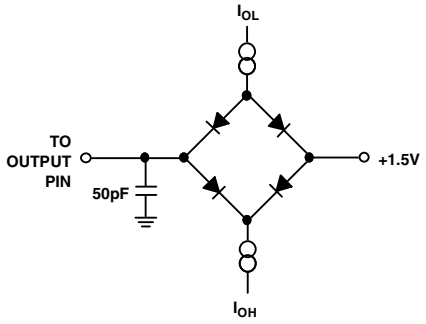


Figure 30. Equivalent Device Loading for AC Measurements (Includes All Fixtures)

Output Drive Characteristics

Figure 31 shows typical I-V characteristics for the output drivers of the ADSP-2106x. The curves represent the current drive capability of the output drivers as a function of output voltage.

240-LEAD MQFP_PQ4/CQFP PIN CONFIGURATION

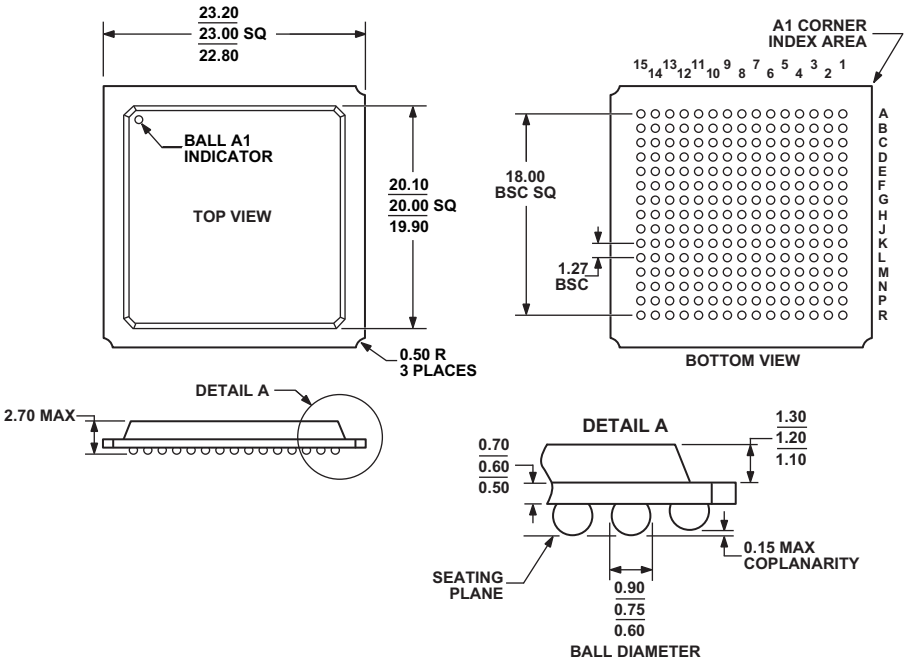
Table 41. ADSP-2106x MQFP_PQ4 and ADSP-21060CZ CQFP Pin Assignments (SP-240-2, QS-240-2A, QS-240-2B)

Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.
TDI	1	ADDR20	41	TCLK0	81	DATA41	121	DATA14	161	L2DAT0	201
$\overline{TRST}$	2	ADDR21	42	TFS0	82	DATA40	122	DATA13	162	L2CLK	202
V_{DD}	3	$\overline{GND}$	43	DR0	83	DATA39	123	DATA12	163	L2ACK	203
TDO	4	ADDR22	44	RCLK0	84	V_{DD}	124	GND	164	NC	204
TIMEXP	5	ADDR23	45	RFS0	85	DATA38	125	DATA11	165	V_{DD}	205
$\overline{EMU}$	6	ADDR24	46	V_{DD}	86	DATA37	126	DATA10	166	L3DAT3	206
ICSA	7	V_{DD}	47	V_{DD}	87	DATA36	127	DATA9	167	L3DAT2	207
FLAG3	8	GND	48	GND	88	GND	128	V_{DD}	168	L3DAT1	208
FLAG2	9	V_{DD}	49	ADRCLK	89	NC	129	DATA8	169	L3DAT0	209
FLAG1	10	ADDR25	50	REDY	90	DATA35	130	DATA7	170	L3CLK	210
FLAG0	11	ADDR26	51	$\overline{HBG}$	91	DATA34	131	DATA6	171	L3ACK	211
GND	12	ADDR27	52	$\overline{CS}$	92	DATA33	132	GND	172	GND	212
ADDR0	13	GND	53	$\overline{RD}$	93	V_{DD}	133	DATA5	173	L4DAT3	213
ADDR1	14	$\overline{MS3}$	54	$\overline{WR}$	94	V_{DD}	134	DATA4	174	L4DAT2	214
V_{DD}	15	$\overline{MS2}$	55	GND	95	GND	135	DATA3	175	L4DAT1	215
ADDR2	16	$\overline{MS1}$	56	V_{DD}	96	DATA32	136	V_{DD}	176	L4DAT0	216
ADDR3	17	$\overline{MS0}$	57	GND	97	DATA31	137	DATA2	177	L4CLK	217
ADDR4	18	$\overline{SW}$	58	CLKIN	98	DATA30	138	DATA1	178	L4ACK	218
GND	19	$\overline{BMS}$	59	ACK	99	GND	139	DATA0	179	V_{DD}	219
ADDR5	20	ADDR28	60	$\overline{DMAG2}$	100	DATA29	140	GND	180	GND	220
ADDR6	21	GND	61	$\overline{DMAG1}$	101	DATA28	141	GND	181	V_{DD}	221
ADDR7	22	V_{DD}	62	PAGE	102	DATA27	142	L0DAT3	182	L5DAT3	222
V_{DD}	23	V_{DD}	63	V_{DD}	103	V_{DD}	143	L0DAT2	183	L5DAT2	223
ADDR8	24	ADDR29	64	$\overline{BR6}$	104	V_{DD}	144	L0DAT1	184	L5DAT1	224
ADDR9	25	ADDR30	65	$\overline{BR5}$	105	DATA26	145	L0DAT0	185	L5DAT0	225
ADDR10	26	ADDR31	66	$\overline{BR4}$	106	DATA25	146	L0CLK	186	L5CLK	226
GND	27	GND	67	$\overline{BR3}$	107	DATA24	147	L0ACK	187	L5ACK	227
ADDR11	28	$\overline{SBTS}$	68	$\overline{BR2}$	108	GND	148	V_{DD}	188	GND	228
ADDR12	29	$\overline{DMAR2}$	69	$\overline{BR1}$	109	DATA23	149	L1DAT3	189	ID2	229
ADDR13	30	$\overline{DMAR1}$	70	GND	110	DATA22	150	L1DAT2	190	ID1	230
V_{DD}	31	$\overline{HBR}$	71	V_{DD}	111	DATA21	151	L1DAT1	191	ID0	231
ADDR14	32	DT1	72	GND	112	V_{DD}	152	L1DAT0	192	LBOOT	232
ADDR15	33	TCLK1	73	DATA47	113	DATA20	153	L1CLK	193	RPBA	233
GND	34	TFS1	74	DATA46	114	DATA19	154	L1ACK	194	$\overline{RESET}$	234
ADDR16	35	DR1	75	DATA45	115	DATA18	155	GND	195	EBOOT	235
ADDR17	36	RCLK1	76	V_{DD}	116	GND	156	GND	196	$\overline{IRQ2}$	236
ADDR18	37	RFS1	77	DATA44	117	DATA17	157	V_{DD}	197	$\overline{IRQ1}$	237
V_{DD}	38	GND	78	DATA43	118	DATA16	158	L2DAT3	198	$\overline{IRQ0}$	238
V_{DD}	39	$\overline{CPA}$	79	DATA42	119	DATA15	159	L2DAT2	199	TCK	239
ADDR19	40	DT0	80	GND	120	V_{DD}	160	L2DAT1	200	TMS	240

Table 42. ADSP-21060CW/21060LCW CQFP Pin Assignments (QS-240-1A, QS-240-1B)

Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.
GND	1	DATA29	41	$\overline{\text{DMAG2}}$	81	ADDR28	121	ADDR5	161	GND	201
DATA0	2	GND	42	ACK	82	$\overline{\text{BMS}}$	122	GND	162	V_{DD}	202
DATA1	3	DATA30	43	CLKIN	83	$\overline{\text{SW}}$	123	ADDR4	163	L4ACK	203
DATA2	4	DATA31	44	GND	84	$\overline{\text{MS0}}$	124	ADDR3	164	L4CLK	204
V_{DD}	5	DATA32	45	V_{DD}	85	$\overline{\text{MS1}}$	125	ADDR2	165	L4DAT0	205
DATA3	6	GND	46	GND	86	$\overline{\text{MS2}}$	126	V_{DD}	166	L4DAT1	206
DATA4	7	V_{DD}	47	$\overline{\text{WR}}$	87	$\overline{\text{MS3}}$	127	ADDR1	167	L4DAT2	207
DATA5	8	V_{DD}	48	$\overline{\text{RD}}$	88	GND	128	ADDR0	168	L4DAT3	208
GND	9	DATA33	49	$\overline{\text{CS}}$	89	ADDR27	129	GND	169	GND	209
DATA6	10	DATA34	50	$\overline{\text{HBG}}$	90	ADDR26	130	FLAG0	170	L3ACK	210
DATA7	11	DATA35	51	REDY	91	ADDR25	131	FLAG1	171	L3CLK	211
DATA8	12	NC	52	ADRCLK	92	V_{DD}	132	FLAG2	172	L3DAT0	212
V_{DD}	13	GND	53	GND	93	GND	133	FLAG3	173	L3DAT1	213
DATA9	14	DATA36	54	V_{DD}	94	V_{DD}	134	ICSA	174	L3DAT2	214
DATA10	15	DATA37	55	V_{DD}	95	ADDR24	135	$\overline{\text{EMU}}$	175	L3DAT3	215
DATA11	16	DATA38	56	RFS0	96	ADDR23	136	TIMEXP	176	V_{DD}	216
GND	17	V_{DD}	57	RCLK0	97	ADDR22	137	TDO	177	NC	217
DATA12	18	DATA39	58	DR0	98	GND	138	V_{DD}	178	L2ACK	218
DATA13	19	DATA40	59	TFS0	99	ADDR21	139	$\overline{\text{TRST}}$	179	L2CLK	219
DATA14	20	DATA41	60	TCLK0	100	ADDR20	140	TDI	180	L2DAT0	220
V_{DD}	21	GND	61	DT0	101	ADDR19	141	TMS	181	L2DAT1	221
DATA15	22	DATA42	62	$\overline{\text{CPA}}$	102	V_{DD}	142	TCK	182	L2DAT2	222
DATA16	23	DATA43	63	GND	103	V_{DD}	143	$\overline{\text{IRQ0}}$	183	L2DAT3	223
DATA17	24	DATA44	64	RFS1	104	ADDR18	144	$\overline{\text{IRQ1}}$	184	V_{DD}	224
GND	25	V_{DD}	65	RCLK1	105	ADDR17	145	$\overline{\text{IRQ2}}$	185	GND	225
DATA18	26	DATA45	66	DR1	106	ADDR16	146	EBOOT	186	GND	226
DATA19	27	DATA46	67	TFS1	107	GND	147	$\overline{\text{RESET}}$	187	L1ACK	227
DATA20	28	DATA47	68	TCLK1	108	ADDR15	148	RPBA	188	L1CLK	228
V_{DD}	29	GND	69	DT1	109	ADDR14	149	LBOOT	189	L1DAT0	229
DATA21	30	V_{DD}	70	$\overline{\text{HBR}}$	110	V_{DD}	150	ID0	190	L1DAT1	230
DATA22	31	GND	71	$\overline{\text{DMAR1}}$	111	ADDR13	151	ID1	191	L1DAT2	231
DATA23	32	$\overline{\text{BR1}}$	72	$\overline{\text{DMAR2}}$	112	ADDR12	152	ID2	192	L1DAT3	232
GND	33	$\overline{\text{BR2}}$	73	$\overline{\text{SBTS}}$	113	ADDR11	153	GND	193	V_{DD}	233
DATA24	34	$\overline{\text{BR3}}$	74	GND	114	GND	154	L5ACK	194	L0ACK	234
DATA25	35	$\overline{\text{BR4}}$	75	ADDR31	115	ADDR10	155	L5CLK	195	L0CLK	235
DATA26	36	$\overline{\text{BR5}}$	76	ADDR30	116	ADDR9	156	L5DAT0	196	L0DAT0	236
V_{DD}	37	$\overline{\text{BR6}}$	77	ADDR29	117	ADDR8	157	L5DAT1	197	L0DAT1	237
V_{DD}	38	V_{DD}	78	V_{DD}	118	V_{DD}	158	L5DAT2	198	L0DAT2	238
DATA27	39	PAGE	79	V_{DD}	119	ADDR7	159	L5DAT3	199	L0DAT3	239
DATA28	40	$\overline{\text{DMAG1}}$	80	GND	120	ADDR6	160	V_{DD}	200	GND	240

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-034-AAJ-2

Figure 40. 225-Ball Plastic Ball Grid Array [PBGA]
(B-225-2)
Dimensions shown in millimeters

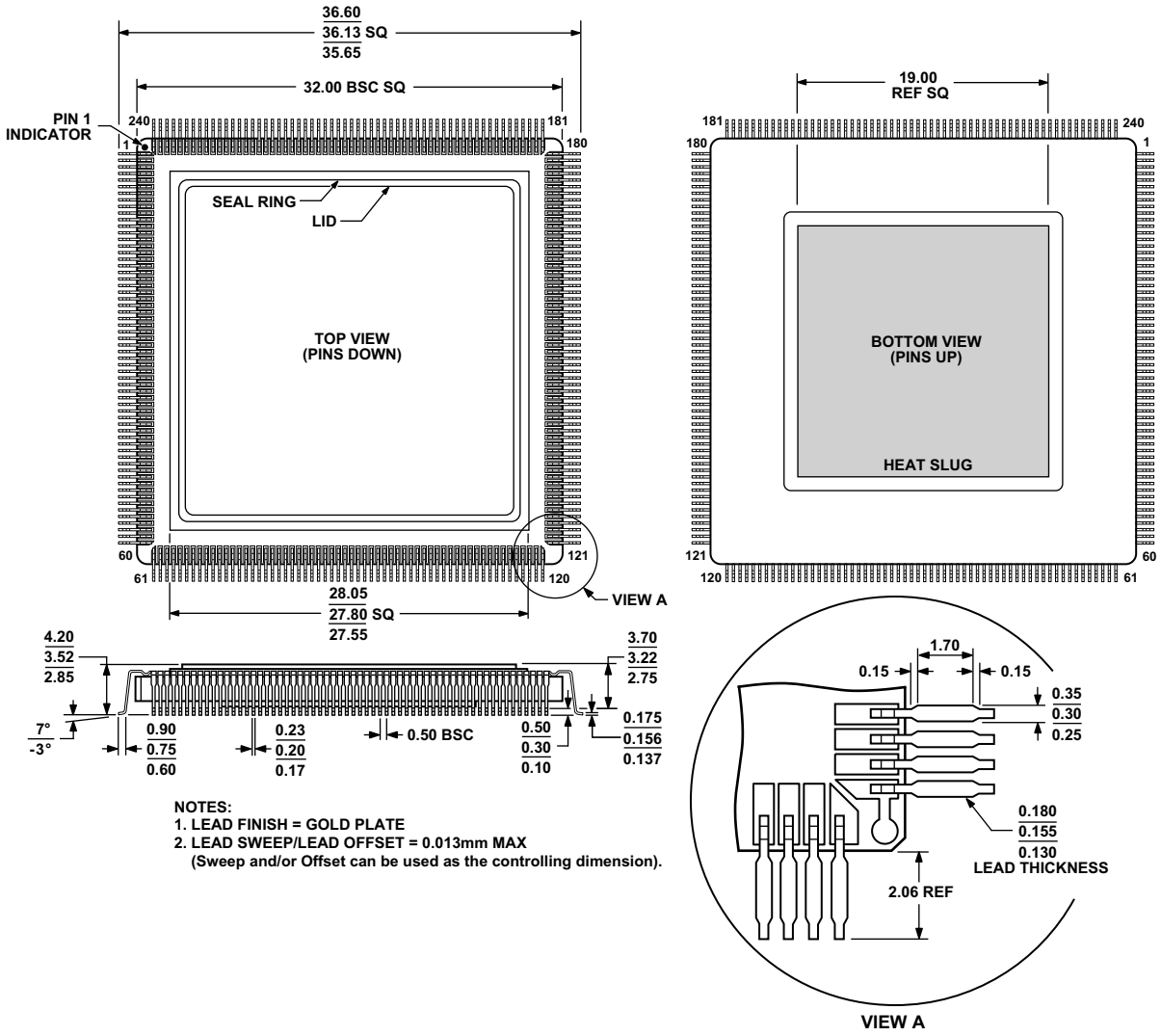


Figure 44. 240-Lead Ceramic Quad Flat Package, Heat Slug Down [CQFP]
(QS-240-1A)
Dimensions shown in millimeters